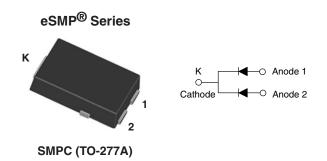
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Hyperfast Rectifier, 2 x 4 A FRED Pt®



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 4 A				
V _R	200 V				
V _F at I _F	0.72 V				
t _{rr (typ.)}	25 ns				
T _J max.	175 °C				
Package	SMPC (TO-277A)				
Circuit configuration	Common cathode				

FEATURES

- Hyperfast recovery time, reduced Q_{rr}, and soft recovery
- 175 °C maximum operating junction temperature
- · Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in snubber, boost, as high frequency rectifiers and freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

MECHANICAL DATA

Case: SMPC (TO-277A)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM R	ATINGS				
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage		V _{RRM}		200	V
Average rectified forward current	per device	I _{F(AV)}	T _{Sp} = 160 °C	8	
Average rectilied forward current	per diode			4	٨
Non-repetitive peak surge current	per device		T _{.1} = 25 °C	130	A
Non-repentive peak surge current	per diode	IFSM	1j = 25 C	70	
Operating junction and storage ten	nperatures	T _J , T _{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	I _R = 100 μA	200	-	-		
Forward voltage, per diode	V	I _F = 4 A	-	0.89	0.95	V	
Forward voltage, per diode	V _F	I _F = 4 A, T _J = 150 °C	-	0.72	0.78		
Reverse leakage current, per diode	I _R	$V_{R} = V_{R}$ rated	-	-	2	μA	
neverse leakage current, per diode		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	6	80		
Junction capacitance	CT	V _R = 200 V	-	17	-	pF	

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COMPLIANT

HALOGEN

FREE



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ /}$	4/μs, V _R = 30 V	-	25	-		
De la construcción de la	+	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		-	-	25		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	18	-	ns	
		T _J = 125 °C		-	27	-		
Deals receiver a current		T _J = 25 °C	$I_F = 4 A$	-	2	-	٨	
Peak recovery current I _{RRM}	IRRM	T _J = 125 °C	dI _F /dt = 200 A/µs V _B = 160 V	-	3.6	-	A	
Reverse recovery charge Q _{rr}	0	T _J = 25 °C		-	18	-	nC	
	Qrr	T _J = 125 °C		-	50	-	no	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Thermal resistance, junction to mount, per leg	R _{thJM}		-	2.5	3.5	°C/W	
Thermal resistance, junction to ambient, per leg	R _{thJA}		-	80	-	°C/W	
Approvimete weight			0.1			g	
Approximate weight			0.0035			oz.	
Marking device		Case style SMPC (TO-277A)		QC	CH2		

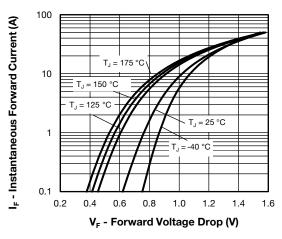


Fig. 1 - Typical Forward Voltage Drop Characteristics

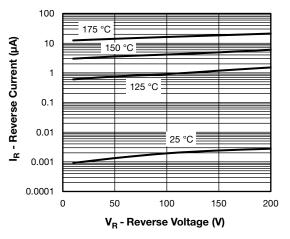
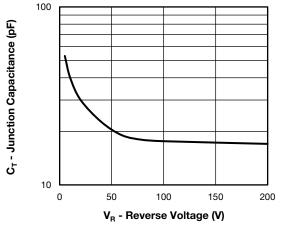


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage





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Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

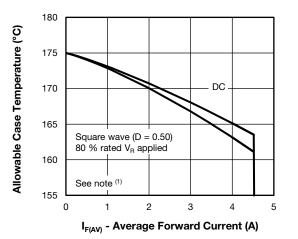


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

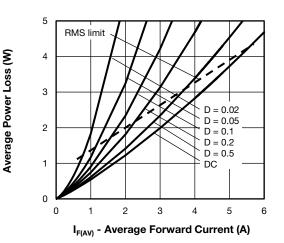


Fig. 5 - Forward Power Loss Characteristics

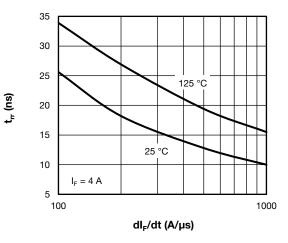


Fig. 6 - Typical Reverse Recovery Time vs. dI_F/dt

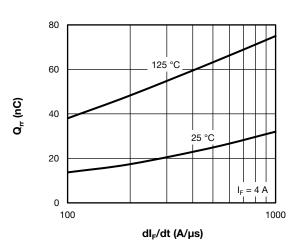


Fig. 7 - Typical Stored Charge vs. dl_F/dt

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ at \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (1 - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ at \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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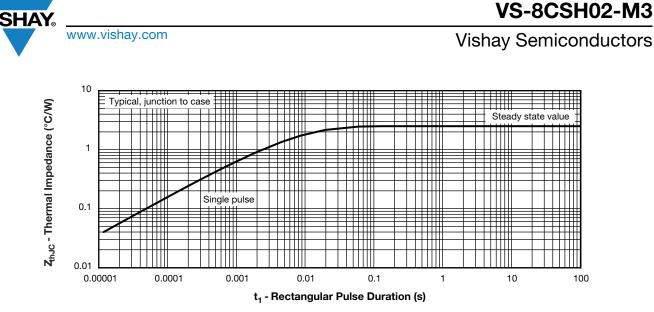


Fig. 8 - Typical Transient Thermal Impedance, Junction to Case

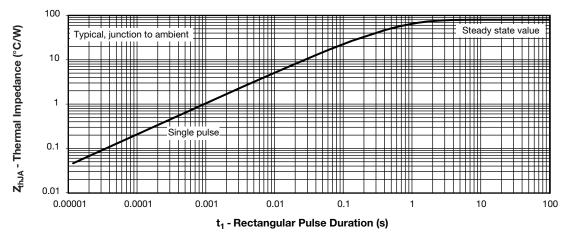
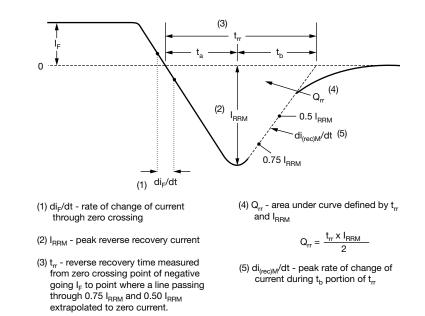
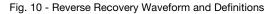


Fig. 9 - Typical Transient Thermal Impedance, Junction to Ambient





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ORDERING INFORMATION TABLE

Device code	VS-	8	с	s	н	02	-M3
	1	2	3	4	5	6	7
	1	- Visl	hay Sen	niconduo	ctors pro	oduct	
	2	- Cur	rent rati	ng (8 =	8 A)		
	3	- Circ	cuit conf	iguratior	า:		
		C =	commo	n catho	de		
	4	- S=	SMPC	package	9		
	5	- Pro	cess typ	e,			
		H =	hyper fa	ast reco	very		
	6	- Vol	tage coo	de (02 =	200 V)		
	7	M3	s = halog	gen-free	, RoHS-	complia	ant, and

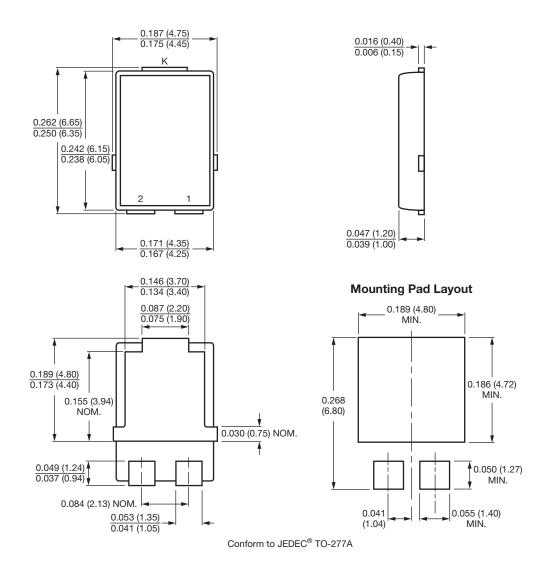
ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-8CSH02-M3/86A	1500	1500	7" diameter plastic tape and reel				
VS-8CSH02-M3/87A	6500	6500	13" diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95570				
Part marking information	www.vishay.com/doc?95565				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96095				



TO-277A (SMPC)

DIMENSIONS in inches (millimeters)





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